



A Product Line of **Diodes Incorporated**

LITE-ON SEMICONDUCTOR ABS10M(LS)

GLASS PASSIVATED SURFACE MOUNT BRIDGE RECTIFIER

REVERSE VOLTAGE – FORWARD CURRENT -

1000 Volts

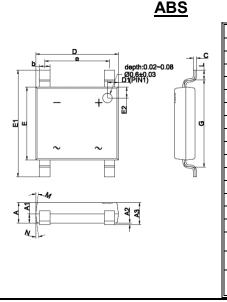
1.0 Ampere

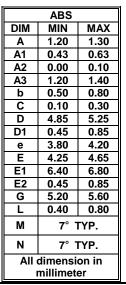
FEATURES

- Ideal for printed circuit board
- Reliable low cost construction utilizing molded plastic technique
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

MECHANICAL DATA

- Package Material: "Green" molding compound, UL flammability classification 94V-0, (No Br. Sb. Cl.) "Halogen-free"
- UL recognized file # E364304
- Polarity indicator: As marked on the body
- Weight: 98 mg (Approximate)
- Marking Code: ABS10M





MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

ABSOLUTE RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Maximum repetitive peak reverse voltage	V _{RRM}	1000	V
Maximum DC blocking voltage	V _{DC}	1000	V
Average rectified output current per device	I _(AV)	1.0	А
Peak forward surge current 8.3ms single half @ T _A =25°C sine-wave superimposed on rated load @ T _A =125°C	I _{FSM}	30 24	А
Peak forward surge current 1ms single half sine- wave superimposed on rated load @ T _A =25°C	I _{FSM}	60 48	А
I^2 t rating for fusing (t = 8.3ms)	l ² t	2.39	A ² S
Operating and storage temperature range	T _J ,T _{STG}	-55 to +150	°C

STATIC ELECTRICAL CHARACTERISTICS

PARAMETER	TEST CONDITION	SYMBOL	Value	UNIT
Forward voltage	$I_F = 0.5A$ $T_A = 25^{\circ}C$	V _F	0.95	V
Leakage current	$V_{R} = 1000V$ $T_{A} = 25^{\circ}C$ $T_{A} = 125^{\circ}C$	I _R	10 100	uA
Typical junction capacitance (No	te 4)	CJ	7.8	pF

THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	Value	UNIT
Typical thermal resistance (Note 5)	RthJ _c RthJ∟	5 17	°C/W
	RthJ _A	48	

Note:

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm

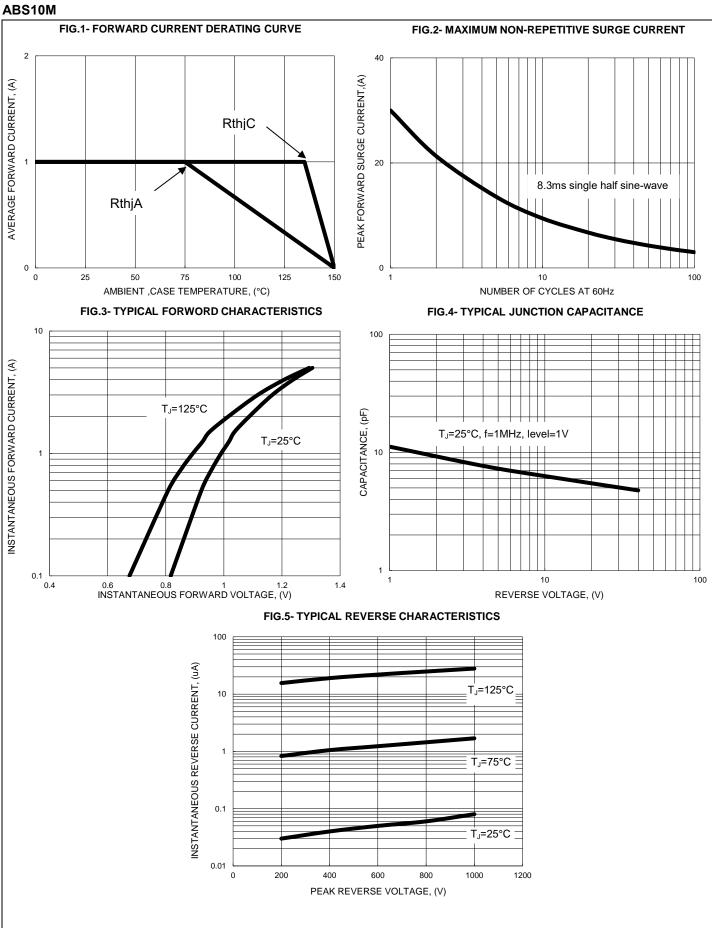
antimony compounds.

4. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

5. Thermal resistance junction to case, lead and ambient in accordance with JESD-51. Unit mounted on glass-epoxy substrate with 1oz/ft2_20x20 mm copper pad per pin with heatsink.



RATING AND CHARACTERISTIC CURVES



LITE-ON

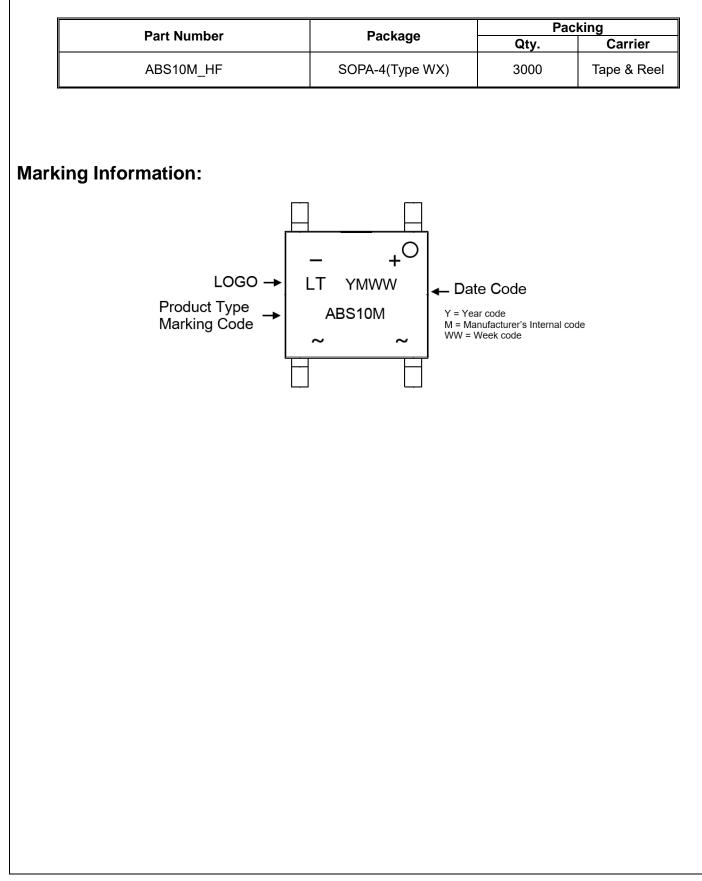
SEMICONDUCTOR

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LITE-ON SEMICONDUCTOR

Ordering Information:





LITE-ON SEMICONDUCTOR

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